# BC808-25LT1G, BC808-40LT1G

# General Purpose Transistors

## **PNP Silicon**

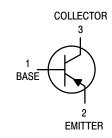
#### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	-25	V
Collector – Base Voltage	V <sub>CBO</sub>	-30	V
Emitter – Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current – Continuous	Ι <sub>C</sub>	-500	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit	
Total Device Dissipation FR-5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W	
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C	
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub>	417	°C/W	
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C	

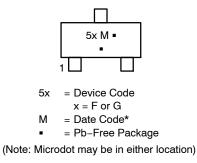
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.

2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



### MARKING DIAGRAM



\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## BC808-25LT1G, BC808-40LT1G

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted.)

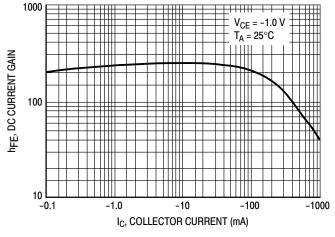
Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•				
Collector – Emitter Breakdown Voltage $(I_{C} = -10 \text{ mA})$		V <sub>(BR)CEO</sub>	-25	-	-	V
Collector – Emitter Breakdown Voltage (V <sub>EB</sub> = 0, I <sub>C</sub> = –10 $\mu$ A)		V <sub>(BR)CES</sub>	-30	-	-	V
Emitter – Base Breakdown Voltage ( $I_E = -1.0 \ \mu A$ )		V <sub>(BR)EBO</sub>	-5.0	-	-	V
Collector Cutoff Current $(V_{CB} = -20 \text{ V})$ $(V_{CB} = -20 \text{ V}, \text{ T}_{J} = 150^{\circ}\text{C})$		I <sub>CBO</sub>			-100 -5.0	nA μA
ON CHARACTERISTICS						
DC Current Gain ( $I_C = -100 \text{ mA}, V_{CE} = -1.0 \text{ V}$ ) ( $I_C = -500 \text{ mA}, V_{CE} = -1.0 \text{ V}$ )	BC808-25LT1G BC808-40LT1G	h <sub>FE</sub>	160 250 40	- - -	400 600 -	_
Collector – Emitter Saturation Voltage ( $I_{C} = -500 \text{ mA}, I_{B} = -50 \text{ mA}$ )		V <sub>CE(sat)</sub>	-	-	-0.7	V
Base – Emitter On Voltage ( $I_C = -500 \text{ mA}, I_B = -1.0 \text{ V}$ )		V <sub>BE(on)</sub>	_	-	-1.2	V
SMALL-SIGNAL CHARACTERISTICS		-				
Current – Gain – Bandwidth Product ( $I_C = -10$ mA, $V_{CE} = -5.0$ Vdc, f = 100 MHz)		f <sub>T</sub>	100	-	-	MHz
Output Capacitance ( $V_{CB} = -10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$ )		C <sub>obo</sub>	_	10	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

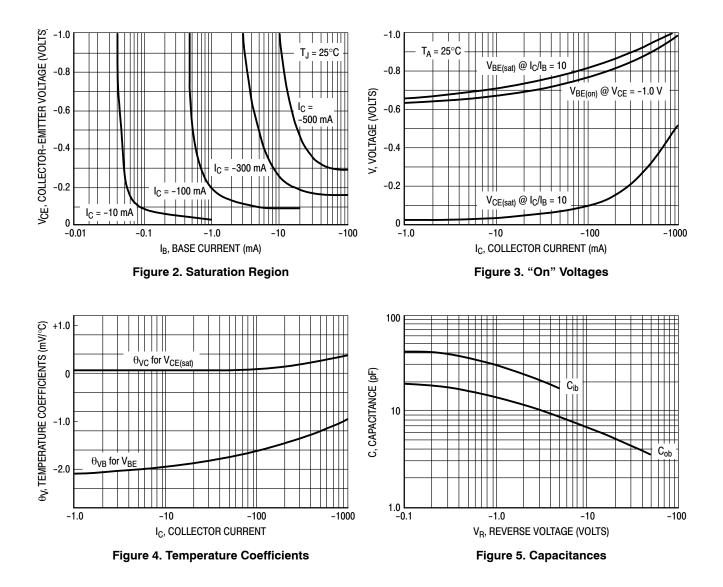
#### **ORDERING INFORMATION**

Device	Specific Marking	Package	Shipping <sup>†</sup>	
BC808-25LT1G	5F	SOT-23	2000 / Tapa & Baal	
SBC808-25LT1G	ЭF	(Pb-Free)	3000 / Tape & Reel	
BC808-40LT1G	5G	SOT-23 (Pb-Free)	3000 / Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

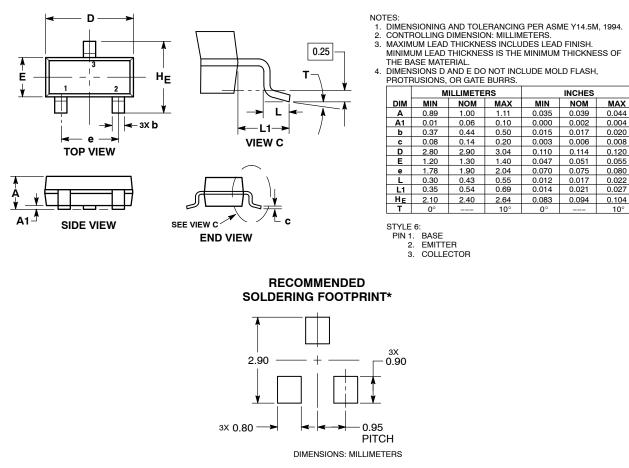






#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AR



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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